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# **ESD Protection Diode** Dual Line Automotive Bus Protector

# NUP2125, SZNUP2125

The SZ/NUP2125 has been designed to protect both CAN and LIN transceivers from ESD and other harmful transient voltage events. This device provides bidirectional protection for each data line with a single compact SC-70 (SOT-323) package, giving the system designer a low cost option for improving system reliability and meeting stringent EMI requirements.

## Features

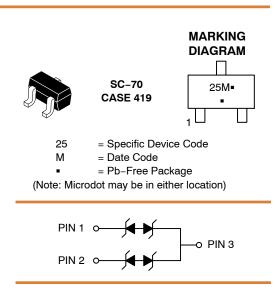
- 200 W Peak Power Dissipation per Line (8/20 µs Waveform)
- Diode Capacitance Matching
- Low Reverse Leakage Current (< 100 nA)
- IEC Compatibility: IEC 61000-4-2 (ESD): Level 4

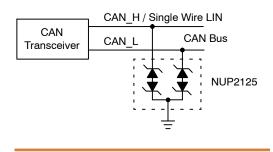
– IEC 61000–4–4 (EFT): 50 A – 5/50 ns

- IEC 61000-4-5 (Lighting) 3.0 A (8/20 μs)
- ISO 7637–1, Nonrepetitive EMI Surge Pulse 2, 8.0 A (1/50 μs)
- ISO 7637–3, Repetitive Electrical Fast Transient (EFT) EMI Surge Pulses, 50 A (5/50 ns)
- Flammability Rating UL 94 V–0
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These are Pb–Free Devices

## Applications

- Automotive Networks
  - ◆ CAN / CAN-FD
  - Low and High-Speed CAN
  - Fault Tolerant CAN
  - + LIN





### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

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# NUP2125, SZNUP2125

## **MAXIMUM RATINGS** (T<sub>J</sub> = $25^{\circ}$ C, unless otherwise specified)

Symbol	Rating	Value	Unit
PPK	Peak Power Dissipation, 8/20 $\mu s$ Double Exponential Waveform (Note 1)	200	W
ТJ	Operating Junction Temperature Range	-55 to 150	°C
TJ	Storage Temperature Range	-55 to 150	°C
ΤL	Lead Solder Temperature (10 s)	260	°C
ESD	Human Body Model (HBM) Machine Model (MM) IEC 61000-4-2 Contact IEC 61000-4-2 Air ISO 10605 150 pF / 2 kΩ Contact ISO 10605 330 pF / 2 kΩ Contact	$\pm 8.0$ $\pm 1.6$ $\pm 30$ $\pm 30$ $\pm 30$ $\pm 30$	kV kV kV kV kV kV

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Non-repetitive current pulse per Figure 1.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V <sub>RWM</sub>	Reverse Working Voltage	(Note 2)	24	-	-	V
$V_{BR}$	Breakdown Voltage	I <sub>T</sub> = 1 mA (Note 3)	27	28.5	32	V
I <sub>R</sub>	Reverse Leakage Current	V <sub>RWM</sub> = 24 V	_	15	100	nA
V <sub>C</sub>	Clamping Voltage	I <sub>PP</sub> = 1 A (8/20 μs Waveform) (Note 4)	_	33.4	36.6	V
V <sub>C</sub>	Clamping Voltage	I <sub>PP</sub> = 3 A (8/20 μs Waveform) (Note 4)	_	44	50	V
$I_{PP}$	Maximum Peak Pulse Current	8/20 μs Waveform (Note 4)	_	-	3.0	А
CJ	Capacitance	$V_R = 0 V$ , f = 1 MHz (Line to GND)	-	7.0	10	pF
		$V_R = 5 V$ , f = 1 MHz (Line to GND)	-	4.5	6.0	pF
		$V_R$ = 5 V, f = 1 MHz (Line to GND), T <sub>A</sub> = +150°C	_	5.0	-	pF
$\Delta C$	Diode Capacitance Matching	V <sub>R</sub> = 0 V, 5 MHz (Note 5)	-	0.26	2	%

#### **ELECTRICAL CHARACTERISTICS** ( $T_J = 25^{\circ}C$ , unless otherwise specified)

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

 Surge protection devices are normally selected according to the working peak reverse voltage (V<sub>RWM</sub>), which should be equal or greater than the DC or continuous peak operating voltage level.

3. V<sub>BR</sub> is measured at pulse test current I<sub>T</sub>.

4. Pulse waveform per Figure 1.

5. ∆C is the percentage difference between C<sub>J</sub> of lines 1 and 2 measured according to the test conditions given in the electrical characteristics table.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>	
NUP2125WTT1G			
SZNUP2125WTT1G*	SC-70	3000 / Tape & Reel	
NUP2125WTT3G	(Pb-Free)	10000 / Tape & Reel	
SZNUP2125WTT3G*			

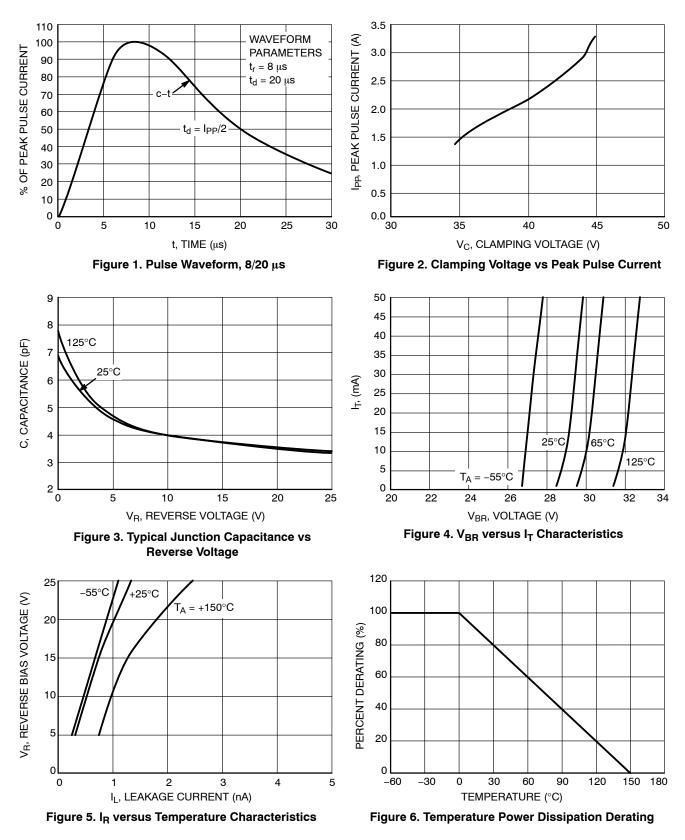
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

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## **TYPICAL PERFORMANCE CURVES**

 $(T_J = 25^{\circ}C \text{ UNLESS OTHERWISE NOTED})$ 



#### **Surge Protection Diode Circuit**

Surge protection diodes provide protection to a transceiver by clamping a surge voltage to a safe level. Surge protection diodes have high impedance below and low impedance above their breakdown voltage. A surge protection Zener diode has its junction optimized to absorb the high peak energy of a transient event, while a standard Zener diode is designed and specified to clamp a steady state voltage.

Figure 7 provides an example of a dual bidirectional surge protection diode array that can be used for protection with the high–speed CAN network. The bidirectional array is created from four identical Zener TVS diodes. The clamping voltage of the composite device is equal to the breakdown voltage of the diode that is reversed biased, plus the diode drop of the second diode that is forwarded biased.

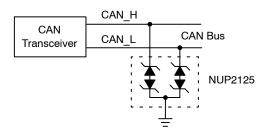
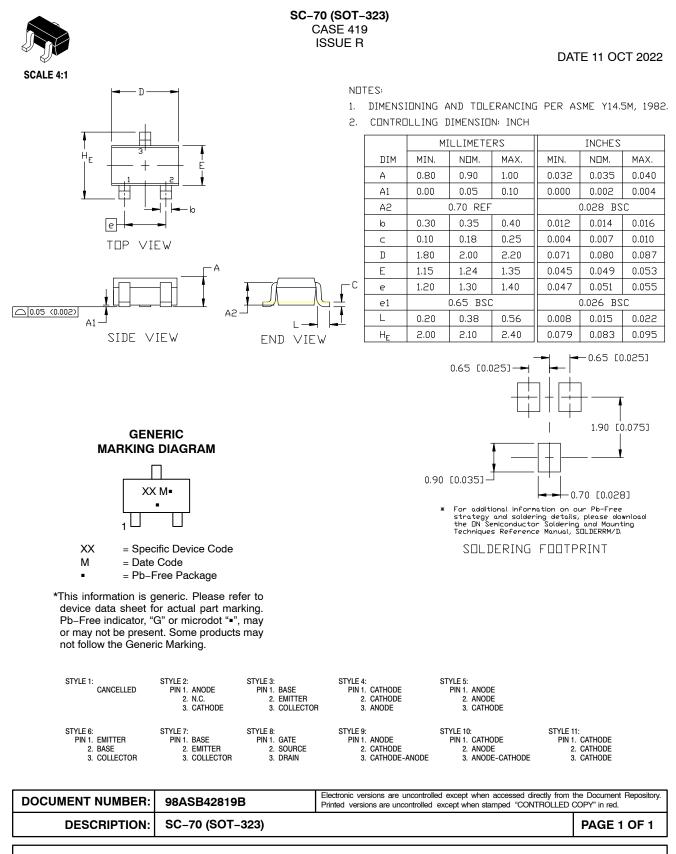


Figure 7. High–Speed and Fault Tolerant CAN Surge Protection Circuit

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